

## MM74HC32 Quad 2-Input OR Gate

### **Features**

- Typical propagation delay: 10ns
- Wide power supply range: 2V–6V
- Low quiescent current: 20µA maximum (74HC Series)
- Low input current: 1µA maximum
- Fanout of 10 LS-TTL loads

### **General Description**

The MM74HC32 OR gates utilize advanced silicon-gate CMOS technology to achieve operating speeds similar to LS-TTL gates with the low power consumption of standard CMOS integrated circuits. All gates have buffered outputs providing high noise immunity and the ability to drive 10 LS-TTL loads. The 74HC logic family is functionally as well as pin-out compatible with the standard 74LS logic family. All inputs are protected from damage due to static discharge by internal diode clamps to V<sub>CC</sub> and ground.

### **Ordering Information**

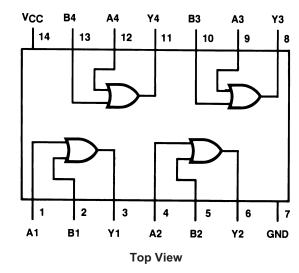
Order Number	Package Number	Package Description
MM74HC32M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
MM74HC32SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
MM74HC32MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
MM74HC32N	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering number.

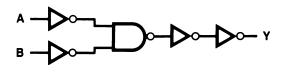
All packages are lead free per JEDEC: J-STD-020B standard.

### **Connection Diagram**

Pin Assignments for DIP, SOIC, SOP and TSSOP



Logic Diagram



Y = A + B (1 of 4)

### Absolute Maximum Ratings<sup>(1)</sup>

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter	Rating
V <sub>CC</sub>	Supply Voltage	–0.5 to +7.0V
V <sub>IN</sub>	DC Input Voltage	–1.5 to V <sub>CC</sub> +1.5V
V <sub>OUT</sub>	DC Output Voltage	–0.5 to V <sub>CC</sub> +0.5V
I <sub>IK</sub> , I <sub>OK</sub>	Clamp Diode Current	±20mA
I <sub>OUT</sub>	DC Output Current, per pin	±25mA
I <sub>CC</sub>	DC V <sub>CC</sub> or GND Current, per pin	±50mA
T <sub>STG</sub>	Storage Temperature Range	–65°C to +150°C
PD	Power Dissipation	
	Note 2	600mW
	S.O. Package only	500mW
TL	Lead Temperature (Soldering 10 seconds)	260°C

Notes:

1. Unless otherwise specified all voltages are referenced to ground.

2. Power Dissipation temperature derating — plastic "N" package: -12mW/°C from 65°C to 85°C.

### **Recommended Operating Conditions**

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. ON Semiconductor does not recommend exceeding them or designing to absolute maximum ratings.

Symbol	Parameter		Max.	Units
V <sub>CC</sub>	Supply Voltage	2	6	V
V <sub>IN</sub> , V <sub>OUT</sub>	DC Input or Output Voltage	0	V <sub>CC</sub>	V
T <sub>A</sub>	Operating Temperature Range	-40	+85	°C
t <sub>r</sub> , t <sub>f</sub>	Input Rise or Fall Times			
	$V_{CC} = 2.0 V$		1000	ns
	$V_{CC} = 4.5V$		500	ns
	$V_{CC} = 6.0 V$		400	ns

<b>DC Electrical</b>	Characteristics <sup>(3)</sup>
----------------------	--------------------------------

			Conditions	T <sub>A</sub> = 25°C		T <sub>A</sub> = -40°C to 85°C	
Symbol	Parameter	V <sub>CC</sub> (V)		Тур	Gua	Guaranteed Limits	
V <sub>IH</sub>	Minimum HIGH Level	2.0			1.5	1.5	V
	Input Voltage	4.5			3.15	3.15	1
		6.0			4.2	4.2	1
V <sub>IL</sub>	Maximum LOW Level	2.0			0.5	0.5	V
	Input Voltage	4.5			1.35	1.35	
		6.0			1.8	1.8	
V <sub>OH</sub>	Minimum HIGH Level	2.0	$V_{IN} = V_{IH} \text{ or } V_{IL},$ $ I_{OUT}  \le 20 \mu A$	2.0	1.9	1.9	V
	Output Voltage	4.5		4.5	4.4	4.4	
		6.0		6.0	5.9	5.9	
		4.5	$V_{IN} = V_{IH} \text{ or } V_{IL},$ $ I_{OUT}  \le 4.0 \text{mA}$	4.7	3.98	3.84	
		6.0	$ V_{IN} = V_{IH} \text{ or } V_{IL},$ $ I_{OUT}  \le 5.2 \text{mA}$	5.2	5.48	5.34	
V <sub>OL</sub>	Maximum LOW Level Output Voltage	2.0	$V_{IN} = V_{IL},$ $ I_{OUT}  \le 20 \ \mu A$	0	0.1	0.1	V
		4.5		0	0.1	0.1	
		6.0		0	0.1	0.1	1
		4.5	$V_{IN} = V_{IL},$ $ I_{OUT}  \le 4.0 \text{mA}$	0.2	0.26	0.33	
		6.0	$V_{IN} = V_{IL},$ $ I_{OUT}  \le 5.2mA$	0.2	0.26	0.33	
I <sub>IN</sub>	Maximum Input Current	6.0	$V_{IN} = V_{CC}$ or GND		±0.1	±1.0	μA
I <sub>CC</sub>	Maximum Quiescent Supply Current	6.0	$V_{IN} = V_{CC}$ or GND, $I_{OUT} = 0\mu A$		2.0	20	μΑ

### Note:

3. For a power supply of 5V ±10% the worst case output voltages (V<sub>OH</sub>, and V<sub>OL</sub>) occur for HC at 4.5V. Thus the 4.5V values should be used when designing with this supply. Worst case V<sub>IH</sub> and V<sub>IL</sub> occur at V<sub>CC</sub> = 5.5V and 4.5V respectively. (The V<sub>IH</sub> value at 5.5V is 3.85V.) The worst case leakage current (I<sub>IN</sub>, I<sub>CC</sub>, and I<sub>OZ</sub>) occur for CMOS at the higher voltage and so the 6.0V values should be used.

## AC Electrical Characteristics

 $V_{CC} = 5V, T_A = 25^{\circ}C, C_L = 15pF, t_r = t_f = 6ns$ 

Symbol	Parameter	Conditions	Тур.	Guaranteed Limit	Units
t <sub>PHL</sub> , t <sub>PLH</sub>	Maximum Propagation Delay		10	18	ns

### **AC Electrical Characteristics**

 $V_{CC}$  = 2.0V to 6.0V,  $C_L$  = 50pF,  $t_r$  =  $t_f$  = 6ns (unless otherwise specified)

				T <sub>A</sub> = 25°C		T <sub>A</sub> = −40°C to 85°C	
Symbol	Parameter	V <sub>CC</sub> (V)	Conditions	Тур	Guara	anteed Limits	Units
t <sub>PHL</sub> , t <sub>PLH</sub>	Maximum Propagation	2.0		30	100	125	ns
	Delay	4.5		12	20	25	
		6.0		9	17	21	
t <sub>TLH</sub> , t <sub>THL</sub>	<sub>TLH</sub> , t <sub>THL</sub> Maximum Output Rise and Fall Time	2.0		30	75	95	ns
		4.5		8	15	19	
		6.0		7	13	16	
C <sub>PD</sub>	Power Dissipation Capacitance <sup>(4)</sup>		(per gate)	50			pF
C <sub>IN</sub>	Maximum Input Capacitance			5	10	10	pF

Note:

4.  $C_{PD}$  determines the no load dynamic power consumption,  $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$ , and the no load dynamic current consumption,  $I_S = C_{PD} V_{CC} f + I_{CC}$ .

ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at <u>www.onsemi.com/site/pdf/Patent-Marking.pdf</u>. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor haves, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such uninten

#### PUBLICATION ORDERING INFORMATION

#### LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor 19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com N. American Technical Support: 800–282–9855 Toll Free USA/Canada Europe, Middle East and Africa Technical Support: Phone: 421 33 790 2910

Japan Customer Focus Center Phone: 81–3–5817–1050 ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative

# **Mouser Electronics**

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

ON Semiconductor:

MM74HC32MTC MM74HC32SJX MM74HC32M MM74HC32N MM74HC32MTCX MM74HC32SJ MM74HC32MX